

### United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE
United States Patent and Trademark Office
Address: COMMISSIONER OF PATENTS AND TRADEMARKS
Washington, D.C. 20231
www.uspto.gov

| APPLICATION NO. FILING DATE  |               | FIRST NAMED INVENTOR | ATTORNEY DOCKET NO.     | CONFIRMATION NO.        |  |  |
|------------------------------|---------------|----------------------|-------------------------|-------------------------|--|--|
| 09/676,197                   | 09/28/2000    | William R. Roche     | 2000.032200             | 9021                    |  |  |
| 75                           | 90 07/31/2002 |                      |                         |                         |  |  |
| J Mike Amerson               |               |                      | EXAMINER                |                         |  |  |
| Williams Morgan & Amerson PC |               |                      | DUONG, KHANH B          |                         |  |  |
| Suite 250<br>7676 Hillmont   |               |                      |                         |                         |  |  |
| Houston, TX 7                | 7040          |                      | ART UNIT                | PAPER NUMBER            |  |  |
| •                            |               |                      | 2822                    | 2822                    |  |  |
|                              |               |                      | DATE MAILED: 07/31/2002 | DATE MAILED: 07/31/2002 |  |  |

Please find below and/or attached an Office communication concerning this application or proceeding.

| •  |  |  |  |  |             |  |  |  |
|--|--|--|--|--|-------------|--|--|--|
|  |  | Application                                      | No.  | plicant(s)   | _/_         |  |  |  |
| Office Action Summary  |  | 09/676,197                                       |  | ROCHE ET AL.   |             |  |  |  |
|  |  | Examiner   |  | Art Unit   |             |  |  |  |
|  |  | Khanh Duo  | ng   | 2822   |             |  |  |  |
| Period fo  | - The MAILING DATE of this communication a<br>r Reply  |  |  |  | 5           |  |  |  |
| A SHO THE M - Exten after: - If the - If NO - Failur   | ORTENED STATUTORY PERIOD FOR REIMAILING DATE OF THIS COMMUNICATION sions of time may be available under the provisions of 37 CFR SIX (6) MONTHS from the mailing date of this communication. period for reply specified above is less than thirty (30) days, a period for reply is specified above, the maximum statutory per et or reply within the set or extended period for reply will, by stately received by the Office later than three months after the many displayment. See 37 CFR 1.704(b). | reply within the statute iod will apply and will | , however, may a reply be tirely minimum of thirty (30) day expire SIX (6) MONTHS from this to become ARANDONE | nely filed  s will be considered timely. the mailing date of this commu (D) (35 U.S.C. § 133). | nication.   |  |  |  |
| 1)[🛛   | Responsive to communication(s) filed on 2  | <u> 24 June 2002</u> .                           |  |  |             |  |  |  |
| 2a) ☐  | This action is FINAL. 2b)⊠   | This action is n                                 |  |  |             |  |  |  |
| 3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213. |  |  |  |  |             |  |  |  |
| -  | on of Claims   |  |  |  |             |  |  |  |
| 4)⊠ Claim(s) <u>1-31</u> is/are pending in the application.  |  |  |  |  |             |  |  |  |
|  | 4a) Of the above claim(s) <u>21-31</u> is/are withdrawn from consideration.  |  |  |  |             |  |  |  |
| 5)   |  |  |  |  |             |  |  |  |
| •  | ☑ Claim(s) <u>1-20</u> is/are rejected.  |  |  |  |             |  |  |  |
| 7)   | Claim(s) is/are objected to.   |  |  |  |             |  |  |  |
|  | Claim(s) are subject to restriction ar   | nd/or election re                                | quirement.   |  |             |  |  |  |
|  | ion Papers   | niner  |  |  |             |  |  |  |
| 9)∐  | The specification is objected to by the Exan The drawing(s) filed on 28 September 2000   | niner.<br>Dis/are: a)∏ acc                       | cented or b)  objecte  | d to by the Examiner.  |             |  |  |  |
| 10)⊠   | The drawing(s) filed on <u>28 September 2000</u>   | to the drawing(s)                                | be held in abevance.   | See 37 CFR 1.85(a).  |             |  |  |  |
| Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).  11) The proposed drawing correction filed on is: a) approved b) disapproved by the Examiner.        |  |  |  |  |             |  |  |  |
| 11)[   | The proposed drawing corrected mod on _  | in reply to this Off                             | ice action.  |  |             |  |  |  |
| If approved, corrected drawings are required in reply to this Office action.  12) The oath or declaration is objected to by the Examiner.  |  |  |  |  |             |  |  |  |
| •  |  |  |  |  |             |  |  |  |
| Priority   | under 35 U.S.C. §§ 119 and 120   | reian priority un                                | der 35 U.S.C. § 119  | (a)-(d) or (f).  |             |  |  |  |
| 13) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).  |  |  |  |  |             |  |  |  |
| a) ☐ All b) ☐ Some * c) ☐ None of:  1.☐ Certified copies of the priority documents have been received.   |  |  |  |  |             |  |  |  |
|  | - and the spirity documents have been received in Application No.  |  |  |  |             |  |  |  |
|  | — use the priority documents have been received in this National Stage   |  |  |  |             |  |  |  |
| *  | application from the International Bureau (PCT Rule 17.2(a)).  * See the attached detailed Office action for a list of the certified copies not received.  |  |  |  |             |  |  |  |
| 14)  | 14) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).   |  |  |  |             |  |  |  |
| a) ☐ The translation of the foreign language provisional application has been received.  15)☐ Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.                     |  |  |  |  |             |  |  |  |
| Attachme   |  |  |  |  |             |  |  |  |
| 1) 🛭 No  | tice of References Cited (PTO-892)<br>tice of Draftsperson's Patent Drawing Review (PTO-94<br>ormation Disclosure Statement(s) (PTO-1449) Paper N  | 18)<br>lo(s)                                     | 4) Interview Summ 5) Notice of Inform 6) Other:  | nary (PTO-413) Paper No(s)<br>al Patent Application (PTO-                                      | 152)        |  |  |  |
| LLS Patent an  | d Trademark Office   |  |  | Part of f  | Paper No. 4 |  |  |  |

Art Unit: 2822

#### **DETAILED ACTION**

#### Election/Restrictions

This Office Action is in response to the Election filed on June 24, 2002.

Accordingly, claims 1-20 were elected with traverse and claims 21-31 are withdrawn from further consideration pursuant to 37 CFR 1.142(b), as being drawn to a nonelected invention, there being no allowable generic or linking claim.

## **Drawings**

The drawings are objected to under 37 CFR 1.83(a). The drawings must show every feature of the invention specified in the claims. Therefore, the feature "at least a portion of said layer of dopant material being *in contact* with said gate dielectric layer" as recited on lines 4 & 5 of Claim 9 must be shown or the feature(s) canceled from the claim(s). No new matter should be entered.

A proposed drawing correction or corrected drawings are required in reply to the Office action to avoid abandonment of the application. The objection to the drawings will not be held in abeyance.

## Claim Objections

Claims 7 and 16 are objected to because of the following informalities: line 5 of both claims, the phrase "layer of dielectric material" should have been --gate dielectric layer--.

Appropriate correction is required.

# Claim Rejections - 35 USC § 112

The following is a quotation of the second paragraph of 35 U.S.C. 112:

Art Unit: 2822

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

Claims 8 and 17 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

Re claims 8 and 17, lines 4 & 5, the phrase "said layer of dopant material defining a region ... between said layer of dopant material and said gate electrode" is confusing since such feature is not described in the specification. According to the specification, it appears that the "gate electrode", as underlined in the phrase above, should have been --gate dielectric layer-- (see page 9, lines 12 & 13).

## Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 1-8, 11-17 and 20 are rejected under 35 U.S.C. 102(b) as being anticipated by Raicu (US 4,561,907).

Raicu discloses a method of forming a semiconductor device (see FIGs. 7 & 10; col. 9, line 57 to col. 10, line 3) comprising the steps of: implanting dopant atoms into a polysilicon layer 62 to define a layer 61 of dopant material in the polysilicon layer 62, the layer 61 of dopant material being completely separate from the substrate 43; and anisotropically etch the polysilicon

Page 4

Application/Control Number: 09/676,197

Art Unit: 2822

layers to define a polysilicon structure comprised of a plurality of sidewalls, the sidewalls having a recess formed therein.

Raicu suggests that such method should be used to form a polysilicon gate electrode 111 above a silicon dioxide gate dielectric layer (see FIG. 14; col. 10, line 63 to col. 11, line 15). Since the same method is being suggested to form the polysilicon gate electrode 111, it should be inherent that the layer of dopant material is completely separate from the layer of gate dielectric material.

Furthermore, Raicu teaches implanting phosphorous atoms into the polysilicon gate electrode layer at a concentration of  $5x10^{16}$  atoms/cm<sup>2</sup> and an energy level of 70 keV (see col. 6, lines 18-20).

## Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

The factual inquiries set forth in *Graham* v. *John Deere Co.*, 383 U.S. 1, 148 USPQ 459 (1966), that are applied for establishing a background for determining obviousness under 35 U.S.C. 103(a) are summarized as follows:

- 1. Determining the scope and contents of the prior art.
- 2. Ascertaining the differences between the prior art and the claims at issue.
- 3. Resolving the level of ordinary skill in the pertinent art.
- 4. Considering objective evidence present in the application indicating obviousness or nonobviousness.

Art Unit: 2822

Claims 9 and 18 are rejected under 35 U.S.C. 103(a) as being unpatentable over Raicu (US 4,561,907) in view of Han (US 6,103,603).

Raicu fails to show at least a portion of the layer of dopant material being in contact with the gate dielectric layer.

Han teaches to implant dopant atoms into a gate electrode layer 13 to define a layer of dopant material 13a in the gate electrode layer 13, wherein at least a portion of the layer of dopant material 13a being in contact with the gate dielectric layer 12 (see FIGs. 1A & 2B; cols. 1 & 2).

Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the process of Raicu with the teaching of Han, since Han expressly states in FIG. 2B and column 2, lines 7-12 that such modification would result with gate electrodes 23a and 23b comprising of a plurality of sidewalls having recesses that are also in contact with the gate dielectric layer 22.

Claims 10 and 19 are rejected under 35 U.S.C. 103(a) as being unpatentable over Raicu (US 4,561,907).

Raicu fails to teach implanting dopant atoms into the polysilicon gate electrode layer at a concentration ranging from approximately  $5x10^{14}$  to  $5x10^{15}$  atoms/cm<sup>2</sup>.

It would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the process of Raicu by selecting a specific dopant concentration for the implantation of dopant atoms into the polysilicon gate electrode layer, since it has been held that where the general conditions of a claim are disclosed in the prior art, discovering the optimum or

Art Unit: 2822

working ranges involves only routine skill in the art. In re Aller, 220 F.2d 454, 456, 105 USPQ 233, 235 (CCPA 1955).

#### Conclusion

The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

Wu et al. (US '975), Hsia et al. (US '391), Lee (US '246) and Nakamura et al. (US '564) disclose relevant methods relating to the instant invention.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Khanh Duong whose telephone number is (703)305-1784. The examiner can normally be reached on Monday - Friday (9:00 AM - 6:00 PM).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Carl Whitehead, Jr. can be reached on (703)308-4940. The fax phone numbers for the organization where this application or proceeding is assigned are (703)305-3431 for regular communications and (703)308-7722 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703)308-0956.

KBD

July 25, 2002

CARL WHITEHEAD, JR.

TECHNOLOGY CENTER 2800